



Porous Burner Ceramics

SiSiC Silicon infiltrated silicon carbide, up to 1400°C. Proprietary manufacturing

technique and material composition.

Structures Foams, filaments, lattices, and many more (custom designed)



Performing High thermal conductivity (120 W/mK), able to bear thermal load up to 3 MW/m²

Any shape Can be manufactured in any required shape

Durability Up to 20'000 hours operation

